



**ZXTN4002Z** 

### **100V NPN LED DRIVING TRANSISTOR IN SOT89**

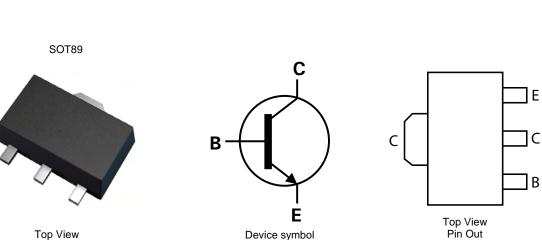
Case material: molded Plastic. "Green" molding Compound.

### **Features**

- $BV_{CEO} > 100V$ •
- Max continuous current I<sub>C (cont)</sub> = 1A
- h<sub>FE</sub> > 100 @ I<sub>C</sub> = 150mA, V<sub>CE</sub> = 200mV .
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

### Applications

LED TV backlight



**Mechanical Data** 

.

.

Case: SOT89

UL Flammability Rating 94V-0

Weight: 0.052 grams (Approximate)

Terminals: Matte Tin Finish

Moisture Sensitivity: Level 1 per J-STD-020

Top View

### Ordering Information (Note 3)

Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
1R9	7	12mm embossed	1000 units
-			1P0 7 12mm omboored

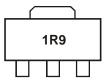
1. No purposefully added lead.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

3. For Packaging Details, go to our website at http://www.diodes.com.

### **Marking Information**

Notes:



1R9 = Product type Marking Code





### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	lc	1	A
Peak Pulse Current (Note 4)	I <sub>CM</sub>	3	A
Base Current	IB	500	mA

### Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

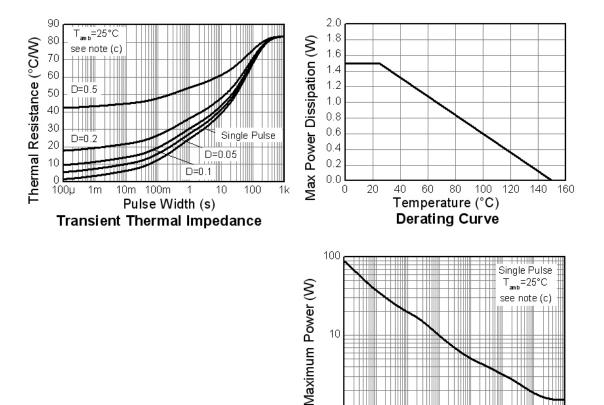
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	83	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R <sub>θJL</sub>	22.44	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

4. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ . Notes:

5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

### Thermal Characteristics and Derating information



100µ

1m

10m 100m

10

- 1 Pulse Width (s) Pulse Power Dissipation

100

1k



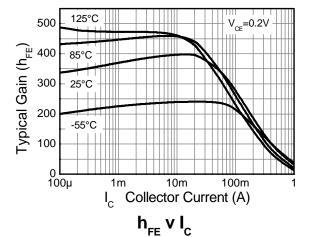
# ated ZXTN4002Z

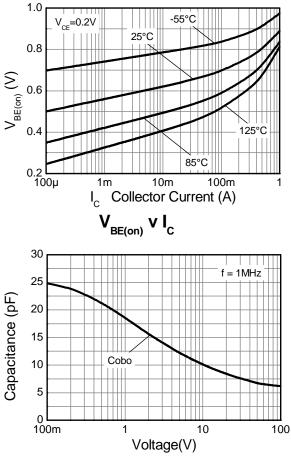
### **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	-	-	V	$I_{\rm C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	100	-	-	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	-	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	I <sub>CBO</sub>	-	-	50	nA	V <sub>CB</sub> = 100V
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	50	nA	$V_{EB} = 7V$
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	60	-	-	-	$I_{C} = 85 \text{mA}, V_{CE} = 0.15 \text{V}$
		100	-	-		I <sub>C</sub> = 150mA, V <sub>CE</sub> = 0.2V
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	-	0.72	0.95	V	I <sub>C</sub> = 150mA, V <sub>CE</sub> = 0.2V
Delay Time	t <sub>(d)</sub>	-	468	-	ns	V <sub>CC</sub> = 80V, I <sub>C</sub> = 150mA, -I <sub>B2</sub> = 1.5mA, V <sub>CE(ON)</sub> = 0.2V
Rise Time	t <sub>(r)</sub>	-	441	-	ns	
Storage Time	t <sub>(s)</sub>	-	1540	-	ns	
Fall Time	t <sub>(f)</sub>	-	251	-	ns	
Storage Time	t <sub>(s)</sub>	-	22	-	ns	V <sub>CC</sub> = 80V, I <sub>C</sub> = 150mA,
Fall Time	t <sub>(f)</sub>	-	204	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 4 \text{V}$

Notes: 7. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ 

**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified



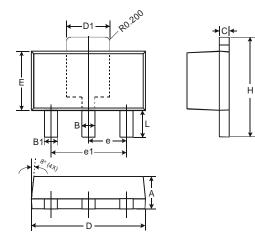


Capacitance v Voltage



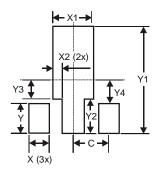


### Package Outline Dimensions



SOT89			
Dim	Min	Max	
Α	1.40	1.60	
В	0.44	0.62	
B1	0.35	0.54	
С	0.35	0.43	
D	4.40	4.60	
D1	1.52	1.83	
E	2.29	2.60	
e	1.50 Typ		
e1	3.00 Typ		
Н	3.94	4.25	
L	0.89	1.20	
All [	All Dimensions in mm		

### Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500



### **ZXTN4002Z**

### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2012, Diodes Incorporated

www.diodes.com

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: ZXTN4002ZTA